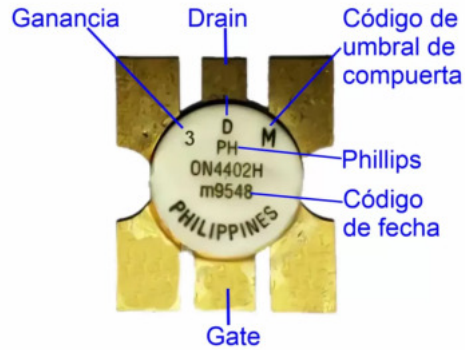
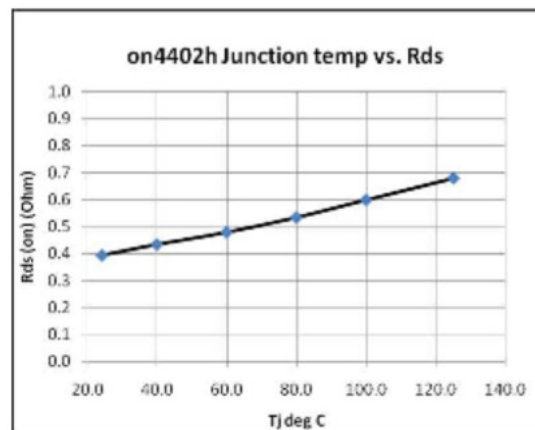
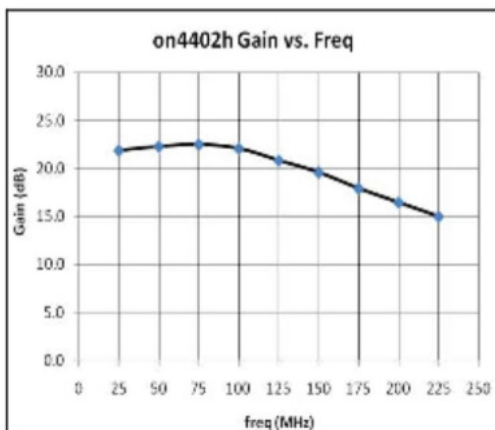
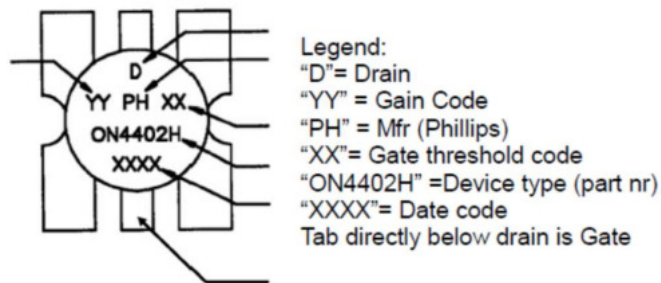




on4402h N-channel enhancement D-MOS
 Drain to source voltage max 110V
 Gate to source voltage max 20V
 Drain current 9A
 Total device dissipation 150W
 Max junction temperature 200C
 Four devices are used with power output of 275 watts peak power



Pout = 100 Watts idq = 50 mAmps
 Vds = 50 Volts ZdL = 9.1 Ohms

On resistance vs. Temperature